

A Product Line of Diodes Incorporated



PI3A3899

#### Description

The DIODES PI3A3899 is a dual double-pole double-throw (DPDT) CMOS switch. It can be used as low power audio and dual SIM card applications. Specified over a wide operating power supply voltage range, +1.65V to +4.3V, the switch has a low On-Resistance of  $2.4\Omega$  at 3.0V.

Control inputs, Ax, tolerate input drive signals up to 5V, independent of supply voltage.

#### Application(s)

- Cell Phones
- PDAs
- Portable Instrumentation Battery Powered
- Computer Peripherals
- Dual SIM Card Switching

#### **Function Truth Table**

$A_0$	Function	A <sub>1</sub>	Function
0	NC <sub>1, 2</sub> Connected to COM <sub>1, 2</sub>	0	NC <sub>3, 4</sub> Connected to COM <sub>3, 4</sub>
1	NO <sub>1, 2</sub> Connected to COM <sub>1, 2</sub>	1	NO <sub>3, 4</sub> Connected to COM <sub>3, 4</sub>

#### **Block Diagram**



#### High Speed, Dual DPDT Analog Switch

#### Features

- CMOS Technology for Analog Applications
- Low On-Resistance: 2.0Ω
- Wide VCC Range: +1.65V to +4.3V
- ICC Maximum  $1\mu A @ TA = +25^{\circ}C$
- Rail-to-Rail Switching Throughout Signal Range
- Fast Switching Speed: 10ns TYP. at 3.0V
- High Off Isolation: -67dB@1MHz
- Crosstalk Rejection: -100dB@1MHz
- Wide Bandwidth: 330MHz
- Interfaces with 1.8V Chipset
- High ESD Performance : 8kV for I/O to GND
- Extended Industrial Temperature Range: -40°C to 85°C
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- For automotive applications requiring specific change control (i.e. parts qualified to AEC-Q100/101/200, PPAP capable, and manufactured in IATF 16949 certified facilities), please <u>contact us</u> or your local Diodes representative.

https://www.diodes.com/quality/product-definitions/

- Packaging (Pb-free & Green):
  - 16-pin, UQFN 1.8mmx2.6mm (ZTA)

Notes:

1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.

2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free. 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.





# **Pin Configuration**

UQFN16 1.8mmx2.6mm Package (Top View)



## **Pin Description**

Pin#	Name	Description	
4, 8, 12, 16	COM <sub>X</sub>	Common Output / Data Port	
1, 5, 9, 13	NC <sub>X</sub>	Data Port (normally connect)	
3, 7, 11, 15	NO <sub>X</sub>	Data Port (normally open)	
2, 10	$A_0, A_1$	Logic Input Control	
6	GND	Ground	
14	VCC	Positive Power Supply	

**Notes**: X = 1, 2, 3, or 4





**Maximum Ratings** 

Storage Temperature	65°C to +150°C
Ambient Temperature	40°C to +85°C
ESD (HBM)	4kV for All Pins
	8kV for I/O to GND
Supply Voltage V <sub>CC</sub>	0.5V to +4.6V
Control Input Voltage (V <sub>INX</sub> )	0 to +5.0V
DC Input Voltage (V <sub>INPUT</sub> )	0.5V to +4.6V
Continuous Current NO/NC/COM	±400mA
Peak Current NO/NC/COM (Pulse at 1ms 10% duty cycle	e)±500mA

**Note:** Stresses greater than those listed under MAXIMUM RATINGS may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect reliability.

#### **Recommended Operating Conditions**

Symbol	Parameter	Conditions	Min.	Тур.	Max.	Unit
V <sub>CC</sub>	Supply Voltage	-	1.65	-	4.3	V
V <sub>INX</sub>	Control Input Voltage	-	0	-	4.3	V
VINPUT	Switch Input Voltage	-	-0.3	-	V <sub>CC</sub>	V
T <sub>A</sub>	Operating Temperature	-	-40	25	85	°C
t <sub>r</sub> , t <sub>f</sub>	Input Rise and Fall Time	Control Input pins $V_{CC} = 2.3V$ to 3.6V	0	-	10	ns/V

Note: Control input must be held HIGH or LOW; it must not float.

## **DC Electrical Characteristics**

 $V_{CC} = 1.65$  to 4.3V, GND=0V,  $V_{IH}$ =+1.6V,  $V_{IL}$ =+0.4V,  $T_A = -40^{\circ}$ C to 85°C, unless otherwise noted. Typical values are at 3V and +25°C.

Symbol	Parameter	Test Conditions		Min.	Тур.	Max.	Units
V <sub>NO</sub> , V <sub>NC</sub> , V <sub>COM</sub>	Analog Signal Range	-		0	-	V <sub>CC</sub>	V
			$V_{\rm CC} = 2.7 V,$	-	2.2	3.6	
R <sub>ON</sub>	On-Resistance	$I_{COM} = 100$ mA, $V_{NO}$ or $V_{NO} = 1V$ . Tost Circuit 1	$V_{\rm CC} = 3.0 V$ ,	-	2.0	3	Ω
		$\mathbf{v}_{\rm NC} = 1 \mathbf{v}$ , rest circuit r	$V_{CC} = 4.3V$	-	1.6	2.4	
AD	On-Resistance Match	$I_{COM} = 100 \text{mA}, V_{NO} \text{ or}$	$V_{\rm CC} = 3.0 V$	-	0.2	-	Ω
$\Delta R_{ON}$	Between Channels	$V_{NC} = 1V$ , Test Circuit 1	$V_{CC} = 4.3V$	-	0.2	-	
	On-Resistance	$I_{COM} = 100 \text{mA}, V_{NO} \text{ or}$	$V_{CC} = 3.0V$	-	0.6		
Ronf	Flatness	$V_{NC} = 0 \sim V_{CC}$ , Test Circuit 1	$V_{\rm CC} = 4.3 V$	-	0.5		Ω
I <sub>OFF (NO)</sub> or I <sub>OFF (NC)</sub>	Source Off Leakage Current	$V_{CC} = 4.3V, V_{NO} \text{ or } V_{NC} = 4.3V/0V,$ $V_{COM} = 0V/4 3V$		-	-	1	
I <sub>NC(ON)</sub> , I <sub>NO(ON)</sub> , I <sub>COM (ON)</sub>	Channel On Leakage Current	$V_{CC} = 4.3V$ , $V_{NO}$ or $V_{NC} = 4.3V/0V$ , $V_{COM} = 0V/4$ 3V or floating		-	-	1	μA
	· · · · · · · · ·	$V_{\rm CC} = 3.0 \text{V}$		1.2	-	-	v
VIH	Input Logic High	$V_{CC} = 4.3V$		1.3	-	-	
**	Input Logic Low	$V_{CC} = 3.0V$		-	-	0.5	
V <sub>IL</sub>		$V_{CC} = 4.3V$		-	-	0.6	
I <sub>IN</sub>	IN Input Leakage Current	$V_{CC} = 4.3V, V_{IN} = 0 \sim 4.3V$		-	-	+/-1	μΑ
t <sub>ON</sub>	Turn-On Time	$R_L = 50\Omega$ , $C_L = 35pF$ , $T_A = 25^{\circ}C$ , See Test Circuit Figure 2		-	8	-	ns
t <sub>OFF</sub>	Turn-Off Time			-	12	-	ns
t <sub>D</sub>	Break-Before-Make Delay	$T_A = 25^{\circ}C$ , See Test Circuit Figure 3		-	9	-	ns



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Symbol	Parameter	Test Conditions		Min.	Тур.	Max.	Units
O <sub>ISO</sub>	NC-NO and COM- NC/NO Off-Isolation			-	-67	-	dB
X <sub>TALK</sub>	Channel-to-Channel Crosstalk			-	-100	-	dB
f <sub>3dB</sub>	3dB Bandwidth	$C_L = 5pF$ , See Test Circuit Figur	re 6	-	330	-	MHz
THD	Total Harmonic Distortion	$V_{CC} = 3.0V$ , f = 20 Hz to 20 kHz, RL = $32\Omega$ , $V_{IN} = 1.0$ VPP		-	0.03	-	%
Q	Charge Injection Select Input to Common I/O	$V_{IN} = GND, R_S = 0, C_L = 1nF, T_A = 25^{\circ}C$ , See Test Circuit Figure 7		-	13	-	pC
C <sub>NC(OFF)</sub>	Off Canazitance	$F = 1MHz$ , $TA = 25^{\circ}C$ , See Test Circuit		-	7	-	
C <sub>NO(OFF)</sub>	On Capachance	Figure 8		-	7	-	рF
Con	On Capacitance	$F = 1MHz$ , $TA = 25^{\circ}C$ , See Test Circuit Figure 9		-	15	-	P
I <sub>CC</sub>	Power Supply Current	$V_{CC} = 4.3V, V_{IN} = 0V \text{ or } V_{CC}$		-	-	1	μA





# **Test Circuits and Timing Diagrams**





Notes: Unused input (NC or NO) must be grounded.



**Figure 2. Switching Times** 



Figure 3. Break Before Make Interval Timing











Figure 5. Channel-to-Channel Cross Talk



Figure 6. Bandwidth



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Figure 7. Charge Injection (Q)



Figure 8. Channel Off Capacitance



Figure 9. Channel On Capacitance

## **Part Marking**







# **Packaging Mechanical**



# For latest package info.

please check: http://www.diodes.com/design/support/packaging/pericom-packaging/packaging-mechanicals-and-thermal-characteristics/

## **Ordering Information**

Part Number	Package Code	Package Description
PI3A3899ZTAEX	ZTA	16-Pin, 1.8x2.6 (UQFN)

#### Notes:

No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.

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3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. E = Pb-free and Green

5. X suffix = Tape/Reel





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